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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/752,642	01/07/2004	Naofumi Nakamura	790001-2042	4109
	7590 02/02/200 AWRENCE & HAUG	9	EXAMINER	
745 FIFTH AV	ENUE- 10TH FL.		CHU, CHRIS C	
NEW YORK, NY 10151			ART UNIT	PAPER NUMBER
			2815	
			MAIL DATE	DELIVERY MODE
			02/02/2009	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

	Application No.	Applicant(s)
	10/752,642	NAKAMURA ET AL.
Office Action Summary	Examiner	Art Unit
	CHRIS C. CHU	2815
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet with the o	correspondence address
A SHORTENED STATUTORY PERIOD FOR REPL WHICHEVER IS LONGER, FROM THE MAILING D. - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period. - Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNICATION .136(a). In no event, however, may a reply be tired will apply and will expire SIX (6) MONTHS from the cause the application to become ABANDONE	N. nely filed the mailing date of this communication. ED (35 U.S.C. § 133).
Status		
Responsive to communication(s) filed on 24 I This action is FINAL . 2b) ☑ This Since this application is in condition for allowed closed in accordance with the practice under	is action is non-final. ance except for formal matters, pro	
Disposition of Claims		
4) Claim(s) 1 - 14 is/are pending in the application 4a) Of the above claim(s) 5 - 10, 13 and 14 is/ 5) Claim(s) is/are allowed. 6) Claim(s) 1 - 3, 11 and 12 is/are rejected. 7) Claim(s) 4 is/are objected to. 8) Claim(s) are subject to restriction and/or are subject to restriction and/or are subjected to by the Examin 10) The drawing(s) filed on is/are: a) accompany are subjected to by the Examin are subjected to by the Examin 10) The drawing(s) filed on is/are: a) accompany are subjected to by the Examin are subjected to be subjected to by the Examin are subjected to be subjecte	/are withdrawn from consideration or election requirement. her. her. herefore bol objected to by the edrawing(s) be held in abeyance. Se	Examiner. e 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the E	•	, ,
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureat * See the attached detailed Office action for a list	nts have been received. nts have been received in Applicat ority documents have been receive au (PCT Rule 17.2(a)).	ion No ed in this National Stage
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal F 6) Other:	ate

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DETAILED ACTION

Response to Pre-Appeal Brief

1. In view of the Pre-appeal brief filed on November 24, 2008, PROSECUTION IS HEREBY REOPENED. A new ground of rejection is set forth below.

To avoid abandonment of the application, appellant must exercise one of the following two options:

- (1) file a reply under 37 CFR 1.11 1 (if this Office action is non-final) or a reply under 37 CFR 1.113 (if this Office action is final); or,
 - (2) request reinstatement of the appeal.

If reinstatement of the appeal is requested, such request must be accompanied by a supplemental appeal brief, but no new amendments, affidavits (37 CFR 1.130, 1.131 or 1.132) or other evidence are permitted. See 37 CFR 1.193(b)(2).

Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 1, 2, 11 and 12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Pramanick et al. (U. S. Pat. No. 6,147,404) in view of Halliyal et al. (U. S. Pat. No. 6,731,006).

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Regarding claim 1, Pramanick et al. discloses in e.g., Fig. 4 a semiconductor device (200; column 2, line 47) having a multilayer structure (see e.g., Fig. 4), comprising:

- at least two wiring layers (101 and 204; column 4, lines 33 and 34), each formed in a wiring groove formed in a corresponding insulating film (105 and 108; column 3, lines 42 44 and column 4, line 39); and
- a via contact (the via contact 202; column 5, line 4) embedded, in a via hole (118; column 4, line 56) formed in an insulating film (116; column 4, lines 4 and 5) formed between the at least two layers (101 and 204) and made of a metal wiring material which is the same as that of the at least two wiring layers (101 and 204; column 4, lines 13 15, column 5, lines 4 6 and see e.g., Fig. 4).

Pramanick et al. does not disclose an additive within the metal wiring material of the via contact. Halliyal et al. teaches in e.g., Fig. 1H a metal wiring material (the material that is located in the via 116; column 6, lines 60 - 65) of the via contact (116; column 6, line 61) containing an additive (the dopant material; column 7, lines 1 - 6). It would have been obvious to one of ordinary skill in the art at the time when the invention was made to apply the dopant material of Halliyal et al. as the specific material to form the additive within the metal wiring material of the via contact of Pramanick et al. as taught by Halliyal et al. to reduce electromigration of copper or the movement of copper atoms along the channels or vias under the influence of electrical current (column 7, lines 6 - 10). Furthermore, the combined structure of Pramanick et al. and Halliyal et al. disclose the following limitation "the additive which is not contained in the metal wiring materials of the at least two wiring layers."

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Regarding claims 2 and 12, Pramanick et al., as modified, discloses in e.g., Fig. 4 the metal wiring material (101 and 204) being Cu (column 4, lines 13 – 15 of Pramanick et al.) and the additive (the dopant material) being Sn, Rh, Zn, A1, Ru, Cr, Pd, In, Mg, Co, Zr, Ti, Ag, Ir, Ni, Ge, Nb, B, Or Hr (column 7, lines 1 – 6 of Halliyal et al.).

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Regarding claim 11, Pramanick et al. discloses in e.g., Fig. 4 a semiconductor device (200) comprising:

- a first metal wiring layer (101) made of a first wiring material (column 4, lines 13 15), formed in a first wiring groove formed in a first insulating film (105) on a semiconductor substrate (the semiconductor substrate of the semiconductor device 200; column 2, lines 24 28);
- a second insulating film (114) on the first insulating film (105) having the first wiring layer (101) embedded therein (see e.g., Fig. 4);
- a via contact (the via contact 202) embedded in a via hole (118) formed in the second insulating film (116; see e.g., Fig. 4), the via contact (the via contact 202) being made of the same wiring material as the first wiring material (column 5, lines 4 6, column 4, lines 13 15 and see e.g., Fig. 4);
- a third insulating film (116) on the second insulating film (114) having the via contact (202) formed therein (see e.g., Fig. 4); and
- a second metal wiring layer (204) embedded in a second wiring groove (the opening within the layer 108) formed in the third insulating film (108; see e.g., Fig. 4), the second metal wiring layer (204) being made of the same metal wiring material as the

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metal wiring material of the first metal wiring layer (101; column 4, lines 13 - 15 and see e.g., Fig. 4).

Pramanick et al. does not disclose an additive within the metal wiring material of the via contact. Halliyal et al. teaches in e.g., Fig. 1H a metal wiring material (the material that is located in the via 116; column 6, lines 60 - 65) of the via contact (116; column 6, line 61) containing an additive (the dopant material; column 7, lines 1 - 6). It would have been obvious to one of ordinary skill in the art at the time when the invention was made to apply the dopant material of Halliyal et al. as the specific material to form the additive within the metal wiring material of the via contact of Pramanick et al. as taught by Halliyal et al. to reduce electromigration of copper or the movement of copper atoms along the channels or vias under the influence of electrical current (column 7, lines 6 - 10). Furthermore, the combined structure of Pramanick et al. and Halliyal et al. disclose the following limitation "the additive which is not contained in the metal wiring materials of the at least two wiring layers."

4. Claim 3 is rejected under 35 U.S.C. 103(a) as being unpatentable over Pramanick et al. and Halliyal et al. as applied to claim 1 above, and further in view of Jan (U. S. Pat. No. 6,861,758).

While Pramanick et al. and Halliyal et al. disclose the use of the metal wiring material (101 and 204) being Al (column 4, lines 13 - 15), Pramanick et al. and Halliyal et al. do not disclose the additive being Cu or Si. Jan teaches in e.g., Fig. 9 an additive (the dopant material; column 2, lines 45 - 16) being Cu or Si (column 2, lines 49 - 51). It would have been obvious to one of ordinary skill in the art at the time when the invention was made to further apply the Cu or

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Si of Jan as the specific material to form the additive within the metal wiring material of the via contact of Pramanick et al. and Halliyal et al. as taught by Jan to inhibit electromigration (column 3, lines 1 - 12).

Allowable Subject Matter

- 5. Claim 4 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
 - (A) Claim 4 contains allowable subject matter because none of references of record teach or suggest, either singularly or in combination, at least the limitation of a metal wiring material being Ag and the additive being Cu.

Response to Arguments

6. Applicant's arguments with respect to claims 1 and 11 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to CHRIS C. CHU whose telephone number is (571)272-1724. The examiner can normally be reached on 11:30 - 8:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Kenneth Parker can be reached on 571-272-2298. The fax phone number for the

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organization where this application or proceeding is assigned is 571-273-8300.

information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated

Chris C. Chu Primary Examiner Art Unit 2815

/Chris C. Chu/ Primary Examiner, Art Unit 2815 Monday, January 26, 2009